SDAS277 - JANUARY 1995

- 3-State Buffer-Type Outputs Drive Bus Lines Directly
- Bus-Structured Pinout
- Inverting-Logic Outputs
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), Standard Plastic (N) and Ceramic (J) 300-mil DIPs, and Ceramic Flat (W) Packages

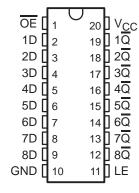
#### description

These octal D-type transparent latches feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

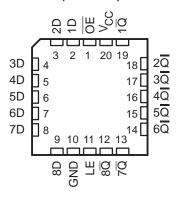
While the latch-enable (LE) input is high, outputs  $(\overline{Q})$  respond to the data (D) inputs. When LE is low, the outputs are latched to retain the data that was set up.

A buffered output-enable  $(\overline{OE})$  input can be used to place the eight outputs in either a normal logic state (high or low) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without interface or pullup components.

SN54ALS580B . . . J OR W PACKAGE SN74ALS580B, SN74AS580 . . . DW OR N PACKAGE (TOP VIEW)



SN54ALS580B . . . FK PACKAGE (TOP VIEW)



OE does not affect internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN54ALS580B is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ALS580B and SN74AS580 are characterized for operation from 0°C to 70°C.

## FUNCTION TABLE (each latch)

	INPUTS		OUTPUT
OE	LE	D	Q
L	Н	Н	L
L	Н	L	н
L	L	Χ	$\overline{Q}_0$
Н	X	Χ	Z

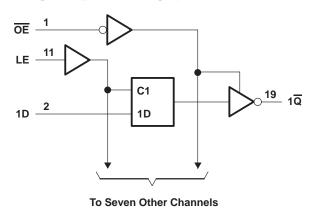
### SN54ALS580B, SN74ALS580B, SN74AS580 OCTAL D-TYPE TRANSPARENT LATCHES WITH 3-STATE OUTPUTS

SDAS277 – JANUARY 1995

#### logic symbol†

#### OE ΕN 11 LE > C1 2 19 1D 1Q 1D 18 3 2D 2<u>Q</u> 17 4 3D 3Q 5 16 4D 4Q 15 6 5D 5Q 7 14 6D $6\overline{Q}$ 8 13 7Q 7D 9 12 8D 8Q

#### logic diagram (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage, V <sub>CC</sub>	7 V
Input voltage, V <sub>I</sub>	7 V
Voltage applied to a disabled 3-state output	
Operating free-air temperature range, T <sub>A</sub> : SN54ALS580B	-55°C to 125°C
SN74ALS580B	0°C to 70°C
Storage temperature range	-65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions

		SN54ALS580B		SN74ALS580B			UNIT	
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
V <sub>IL</sub>	Low-level input voltage			0.7			0.8	V
ІОН	High-level output current			-1			-2.6	mA
l <sub>OL</sub>	Low-level output current			12			24	mA
t <sub>W</sub>	Pulse duration, LE high	15			15			ns
t <sub>su</sub>	Setup time, data before LE↓	20			10			ns
th	Hold time, data after LE↓	12			10			ns
TA	Operating free-air temperature	-55		125	0		70	°C

<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

SDAS277 – JANUARY 1995

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	PARAMETER TEST CONDITIONS		SNS	4ALS58	0B	SN74ALS580		0B	UNIT
PARAWETER	lESI CC	MUITIONS	MIN TYPT MAX		MAX	MIN	TYP†	MAX	UNIT
VIK	V <sub>CC</sub> = 4.5 V,	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V
	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V <sub>CC</sub> -2	)		V <sub>CC</sub> -2	!		
Voн	V <sub>CC</sub> = 4.5 V	$I_{OH} = -1 \text{ mA}$	2.4	3.3					V
	vCC = 4.5 v	$I_{OH} = -2.6 \text{ mA}$				2.4	3.2		
Va	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 12 mA		0.25	0.4		0.25	0.4	V
VOL	VCC = 4.5 V	I <sub>OL</sub> = 24 mA					0.35	0.5	٧
lozh	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.7 V			20			20	μΑ
lozL	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0.4 V			-20			-20	μΑ
l <sub>l</sub>	$V_{CC} = 5.5 \text{ V},$	V <sub>I</sub> = 7 V			0.1			0.1	mA
lіН	$V_{CC} = 5.5 \text{ V},$	V <sub>I</sub> = 2.7 V			20			20	μΑ
I <sub>IL</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.4 V			-0.13			-0.1	mA
I <sub>O</sub> ‡	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.25 V	-20		-112	-30		-112	mA
		Outputs high		10	17		10	17	mA
ICC	V <sub>CC</sub> = 5.5 V	Outputs low		16	26		16	26	
		Outputs disabled		17	29		17	29	

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

#### switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>(</sub> C <sub>I</sub> R1 R2 T <sub>A</sub>	UNIT			
			SN54AL	S580B	SN74ALS580B		
			MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	D	ā	3	26	3	18	ns
t <sub>PHL</sub>	D	Q	3	15	3	14	115
t <sub>PLH</sub>	LE	Q	8	29	6	22	ns
t <sub>PHL</sub>	LL	Q	4	22	6	21	115
<sup>t</sup> PZH	ŌĒ	_	4	25	3	18	
tPZL	OE .	ℚ	4	21	4	18	ns
<sup>t</sup> PHZ	ŌĒ	Q	2	12	1	10	ns
t <sub>PLZ</sub>	OE .		3	22	1	15	115

<sup>§</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



<sup>&</sup>lt;sup>‡</sup> The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

#### SN54ALS580B, SN74ALS580B, SN74AS580 OCTAL D-TYPE TRANSPARENT LATCHES **WITH 3-STATE OUTPUTS**

SDAS277 – JANUARY 1995

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V <sub>CC</sub>	7 V
Input voltage, V <sub>I</sub>	7 V
Voltage applied to a disabled 3-state output	5.5 V
Operating free-air temperature range, T <sub>A</sub> : SN74AS580	0°C to 70°C
Storage temperature range	-65°C to 150°C

#### recommended operating conditions

		SN74AS580			UNIT
		MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	V
$V_{IH}$	High-level input voltage	2			V
V <sub>IL</sub>	Low-level input voltage			0.8	V
IOH	High-level output current			-15	mA
loL	Low-level output current			48	mA
t <sub>W</sub> *	Pulse duration, LE high	2			ns
t <sub>su</sub> *	Setup time, data before LE↓	2			ns
th*	Hold time, data after LE↓	3			ns
T <sub>A</sub>	Operating free-air temperature	0		70	°C

<sup>\*</sup> On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DARAMETER	TEST CONDIT	SI	SN74AS580			
PARAMETER	TEST CONDIT	TEST CONDITIONS				UNIT
VIK	V <sub>CC</sub> = 4.5 V,	$I_{I} = -18 \text{ mA}$			-1.2	V
Vou	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -2 \text{ mA}$	V <sub>CC</sub> -2	2		٧
VOH	$V_{CC} = 4.5 V,$	$I_{OH} = -15 \text{ mA}$	2.4	3.3		V
VOL	$V_{CC} = 4.5 V,$	$I_{OL} = 48 \text{ mA}$		0.33	0.5	V
lozh	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.7 V			50	μΑ
lozL	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0.4 V			-50	μΑ
l <sub>l</sub>	$V_{CC} = 5.5 V,$	V <sub>I</sub> = 7 V			0.1	mA
lН	$V_{CC} = 5.5 V,$	V <sub>I</sub> = 2.7 V			20	μΑ
I <sub>ΙL</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.4 V			-0.5	mA
ΙΟ <sup>§</sup>	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.25 V	-30		-112	mA
		Outputs high		62	100	
Icc	V <sub>CC</sub> = 5.5 V	Outputs low		65	106	mA
		Outputs disabled		71	115	

<sup>‡</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .



<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>§</sup> The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

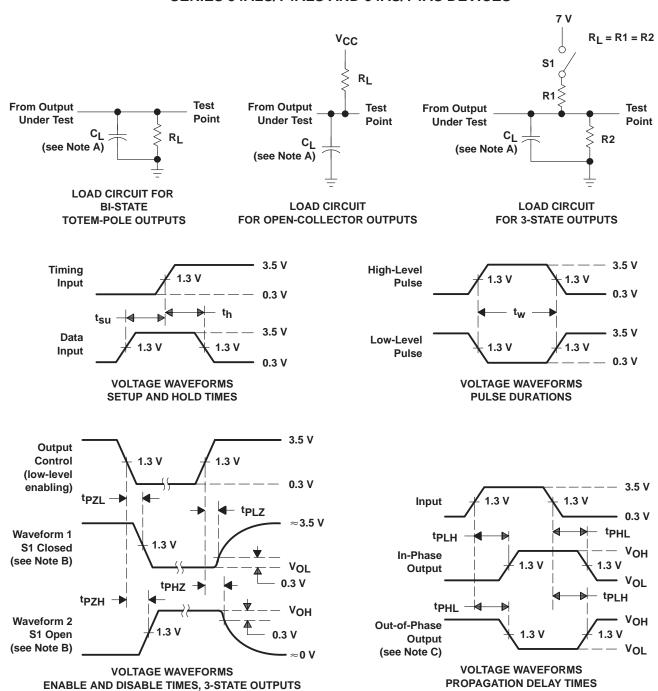
#### switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 4.5 C <sub>L</sub> = 50 pF R1 = 500 Ω R2 = 500 Ω T <sub>A</sub> = MIN to	UNIT	
			MIN	MAX	
t <sub>PLH</sub>	D	Q	3	7.5	ns
t <sub>PHL</sub>		Q	3	7	115
t <sub>PLH</sub>	LE	Q	5	9	
<sup>t</sup> PHL	LE	l q	4	8	ns
<sup>t</sup> PZH	<del>OE</del>	Q	2	6.5	
tPZL	) OE	l q	4	9.5	ns
t <sub>PHZ</sub>	<del>OE</del>	Q	2	6.5	
<sup>t</sup> PLZ	]	l <sup>~</sup>	2	7	ns

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

SDAS277 - JANUARY 1995

#### PARAMETER MEASUREMENT INFORMATION SERIES 54ALS/74ALS AND 54AS/74AS DEVICES



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- D. All input pulses have the following characteristics:  $PRR \le 1$  MHz,  $t_f = t_f = 2$  ns, duty cycle = 50%.
- E. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms







28-Feb-2005

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finisl	n MSL Peak Temp <sup>(3)</sup>
84012022A	ACTIVE	LCCC	FK	20	1	None	Call TI	Level-NC-NC-NC
8401202RA	ACTIVE	CDIP	J	20	1	None	Call TI	Level-NC-NC-NC
8401202SA	ACTIVE	CFP	W	20	1	None	Call TI	Level-NC-NC-NC
SN54ALS580BJ	ACTIVE	CDIP	J	20	1	None	Call TI	Level-NC-NC-NC
SN74ALS580BDW	ACTIVE	SOIC	DW	20	25	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
SN74ALS580BDWR	ACTIVE	SOIC	DW	20	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
SN74ALS580BN	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN74ALS580BN3	OBSOLETE	PDIP	N	20		None	Call TI	Call TI
SN74ALS580BNSR	ACTIVE	SO	NS	20	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
SN74AS580DW	OBSOLETE	SOIC	DW	20		None	Call TI	Call TI
SN74AS580DWR	OBSOLETE	SOIC	DW	20		None	Call TI	Call TI
SN74AS580N	OBSOLETE	PDIP	N	20		None	Call TI	Call TI
SNJ54ALS580BFK	ACTIVE	LCCC	FK	20	1	None	Call TI	Level-NC-NC-NC
SNJ54ALS580BJ	ACTIVE	CDIP	J	20	1	None	Call TI	Level-NC-NC-NC
SNJ54ALS580BW	ACTIVE	CFP	W	20	1	None	Call TI	Level-NC-NC-NC

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### **IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

Copyright © 2005, Texas Instruments Incorporated

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.